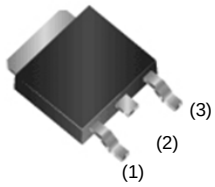
RSD201N10

Nch 100V 20A Power MOSFET Datasheet

V_{DSS}	100V
$R_{DS(on)}$ (Max.)	46mΩ
I_D	20A
P_D	20W

●Outline

CPT3
(SC-63)
<SOT-428>



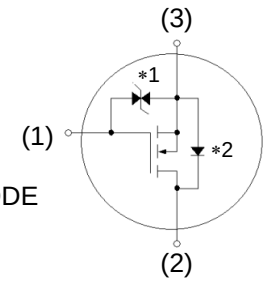
●Features

1) Low on-resistance.
2) Fast switching speed.
3) Drive circuits can be simple.
4) Parallel use is easy.
5) Pb-free lead plating ; RoHS compliant
6) 100% Avalanche tested

●Inner circuit

(1) Gate
(2) Drain
(3) Source

∗1 ESD PROTECTION DIODE
∗2 BODY DIODE



●Application

Switching Power Supply
Automotive Motor Drive
Automotive Solenoid Drive

●Packaging specifications

Type	Packaging	Taping
	Reel size (mm)	330
	Tape width (mm)	16
	Basic ordering unit (pcs)	2,500
	Taping code	TL
	Marking	201N10

●Absolute maximum ratings(T_a = 25°C)

Parameter		Symbol	Value	Unit
Drain - Source voltage		V_{DSS}	100	V
Continuous drain current	T_c = 25°C	I_D *1	±20	A
	T_c = 100°C	I_D *1	±10	A
Pulsed drain current		$I_{D,pulse}$ *2	±80	A
Gate - Source voltage		V_{GSS}	±20	V
Avalanche energy, single pulse		E_{AS} *3	14.6	mJ
Avalanche current		I_{AR} *3	10	A
Power dissipation	T_c = 25°C	P_D	20	W
	T_a = 25°C *4	P_D	0.85	W
Junction temperature		T_j	150	°C
Range of storage temperature		T_{stg}	−55 to +150	°C

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●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - ambient	R_{thJC}	-	-	6.25	°C/W
Thermal resistance, junction - ambient *4	R_{thJA}	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T_{sold}	-	-	265	°C

●Electrical characteristics(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D = 1mA	100	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS} = 100V, V_{GS} = 0V T_j = 25°C	-	-	1	μA
		V_{DS} = 100V, V_{GS} = 0V T_j = 125°C	-	-	100	
Gate - Source leakage current	I_{GSS}	V_{GS} = ±20V, V_{DS} = 0V	-	-	±10	μA
Gate threshold voltage	$V_{GS\ (th)}$	V_{DS} = 10V, I_D = 1mA	1.0	-	2.5	V
Static drain - source on - state resistance	$R_{DS(on)}$ *5	V_{GS} = 10V, I_D = 20A	-	33	46	mΩ
		V_{GS} = 4.0V, I_D = 20A	-	36	50	
		V_{GS} = 10V, I_D = 20A T_j = 125°C	-	60	84	
Forward transfer admittance	g_{fs}	V_{DS} = 10V, I_D = 20A	15	30	-	S

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●**Electrical characteristics**(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C_{iss}	V_{GS} = 0V	-	2100	-	pF
Output capacitance	C_{oss}	V_{DS} = 25V	-	180	-	
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	120	-	
Turn - on delay time	$t_{d(on)}$ *5	$V_{DD} \simeq$ 50V, V_{GS} = 10V	-	100	-	ns
Rise time	t_r *5	I_D = 10A	-	35	-	
Turn - off delay time	$t_{d(off)}$ *5	R_L = 12Ω	-	150	-	
Fall time	t_f *5	R_G = 10Ω	-	100	-	

●**Gate Charge characteristics**(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q_g *5	$V_{DD} \simeq$ 50V	-	55	-	nC
Gate - Source charge	Q_{gs} *5	I_D = 20A	-	5.5	-	
Gate - Drain charge	Q_{gd} *5	V_{GS} = 10V	-	12.5	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} \simeq$ 30V, I_D = 20A	-	2.7	-	V

●**Body diode electrical characteristics** (Source-Drain)(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous source current	I_S *1	T_c = 25°C	-	-	14	A
Pulsed source current	I_{SM} *2		-	-	80	A
Forward voltage	V_{SD} *5	V_{GS} = 0V, I_S = 20A	-	-	1.5	V
Reverse recovery time	t_{rr} *5	I_S = 20A di/dt = 100A/μs	-	65	-	ns
Reverse recovery charge	Q_{rr} *5		-	144	-	μC

*1 Limited only by maximum temperature allowed.

*2 Pw ≤ 10μs, Duty cycle ≤ 1%

*3 L ≃ 100μH, V_{DD} = 50V, Rg = 10Ω, starting T_j = 25°C

*4 Mounted on a epoxy PCB FR4 (20mm × 30mm × 0.8mm)

*5 Pulsed

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●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

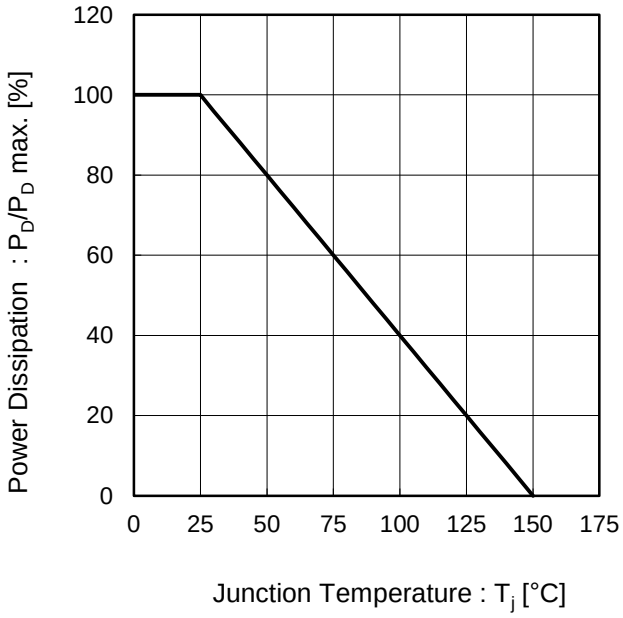


Fig.2 Maximum Safe Operating Area

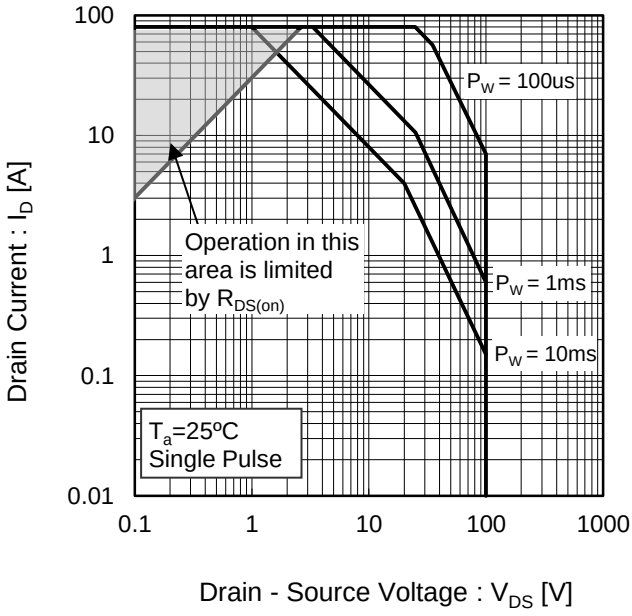
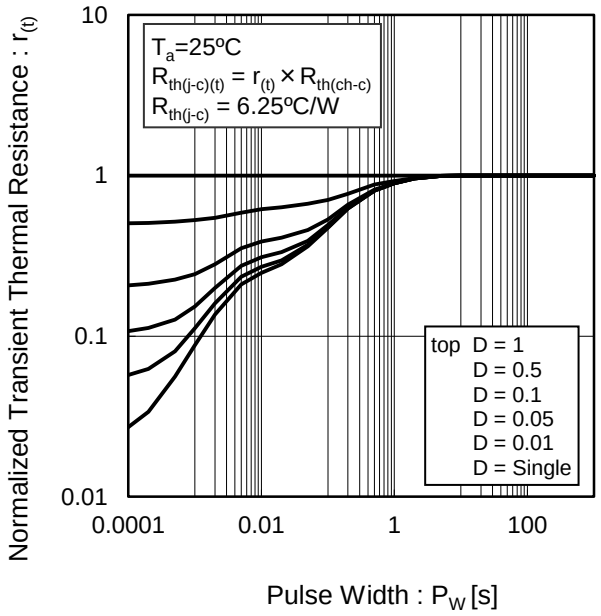


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



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●Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

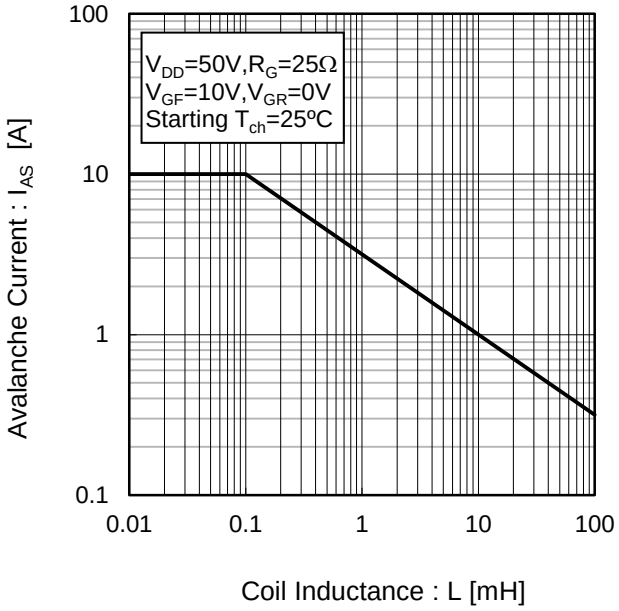


Fig.5 Avalanche Energy Derating Curve vs Junction Temperature

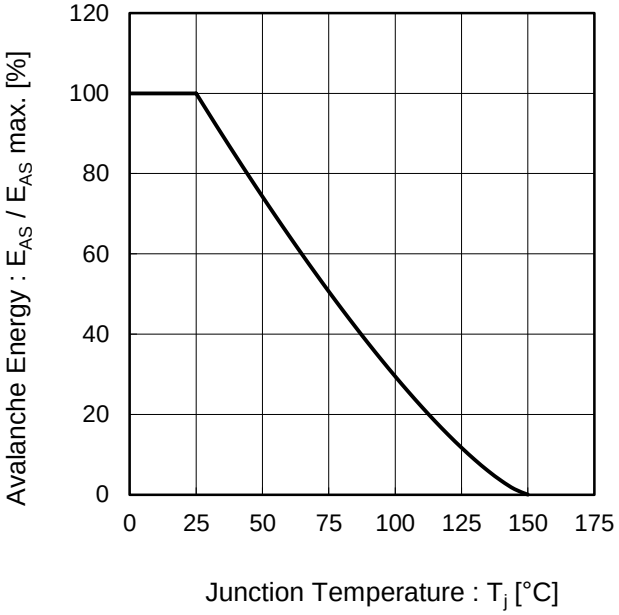


Fig.6 Typical Output Characteristics(I)

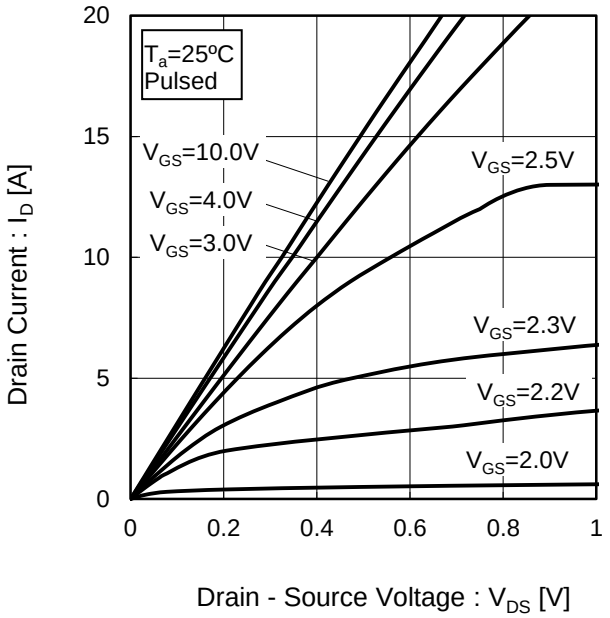
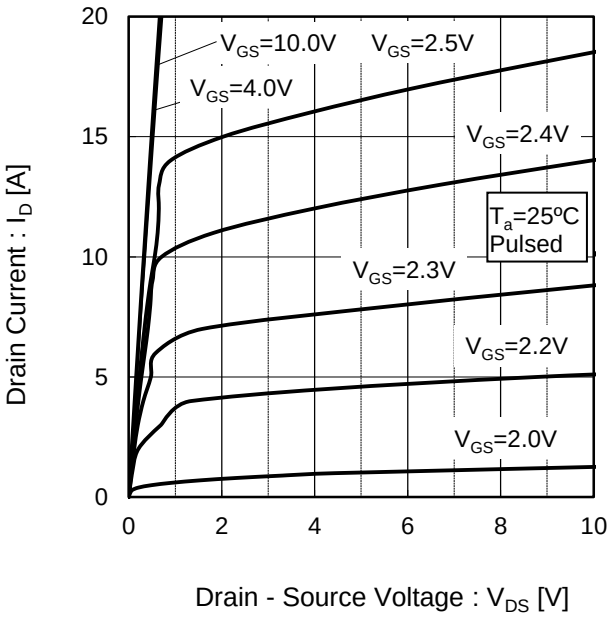


Fig.7 Typical Output Characteristics(II)



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●Electrical characteristic curves

Fig.8 Breakdown Voltage vs. Junction Temperature

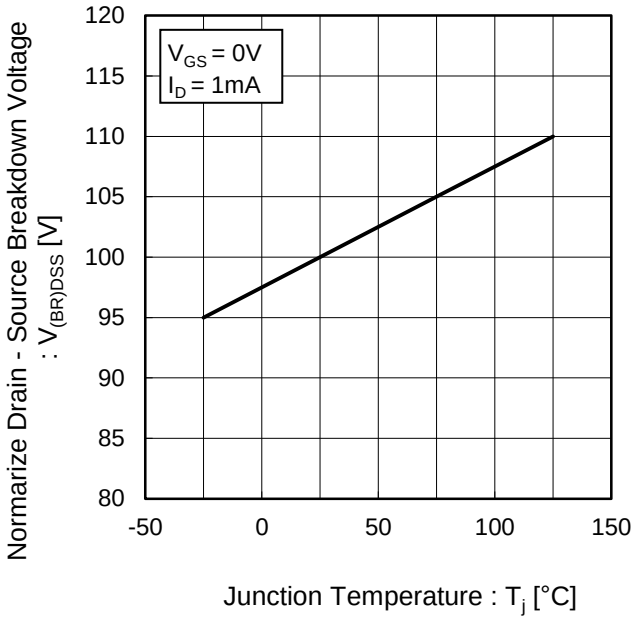


Fig.9 Typical Transfer Characteristics

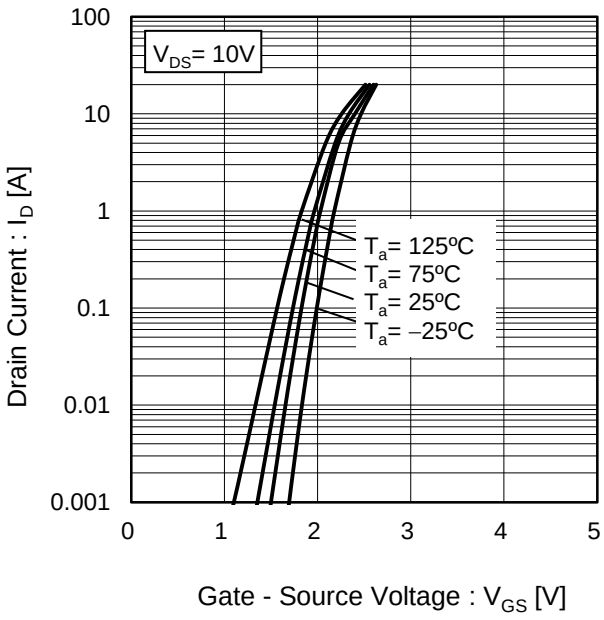


Fig.10 Gate Threshold Voltage vs. Junction Temperature

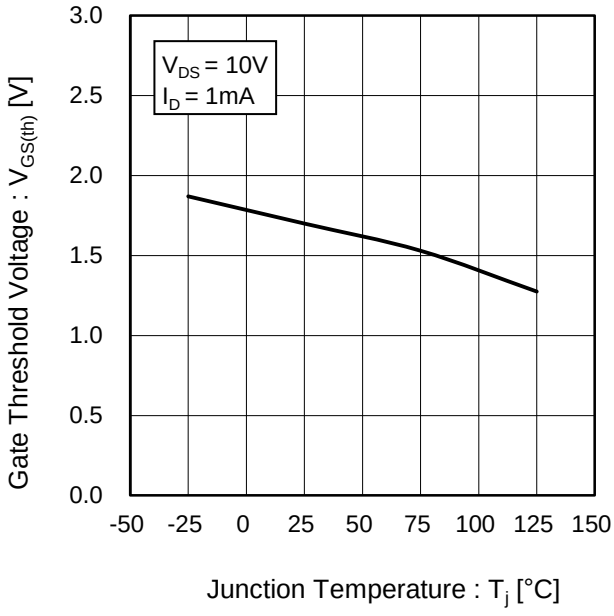
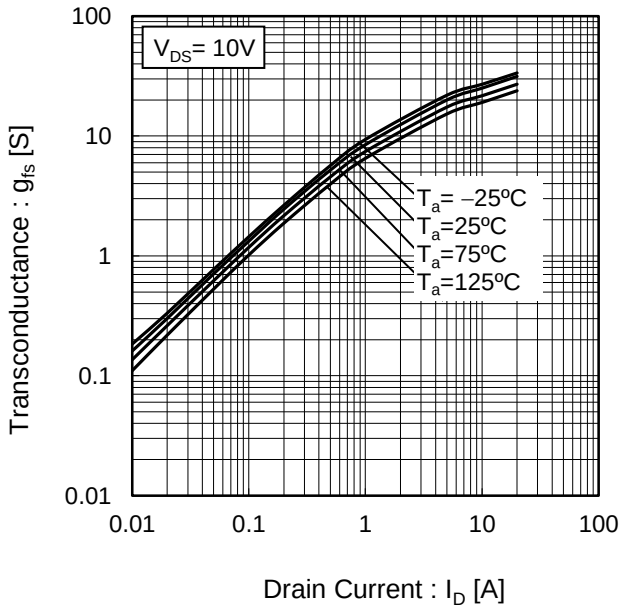


Fig.11 Transconductance vs. Drain Current



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●Electrical characteristic curves

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

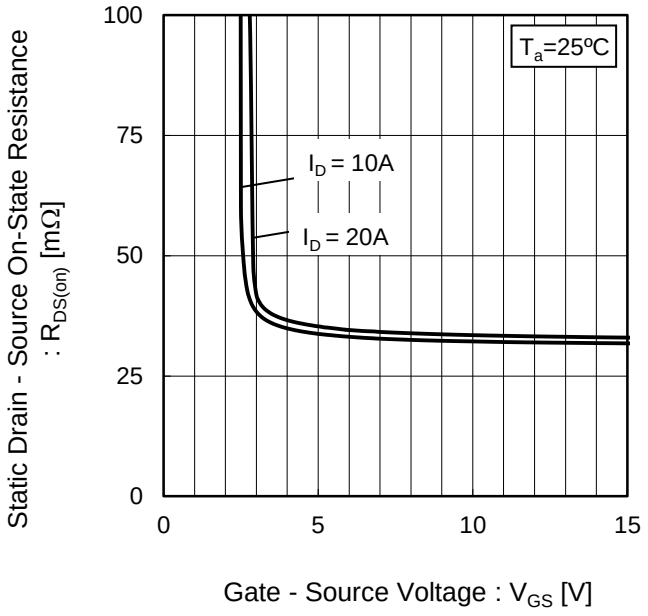


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)

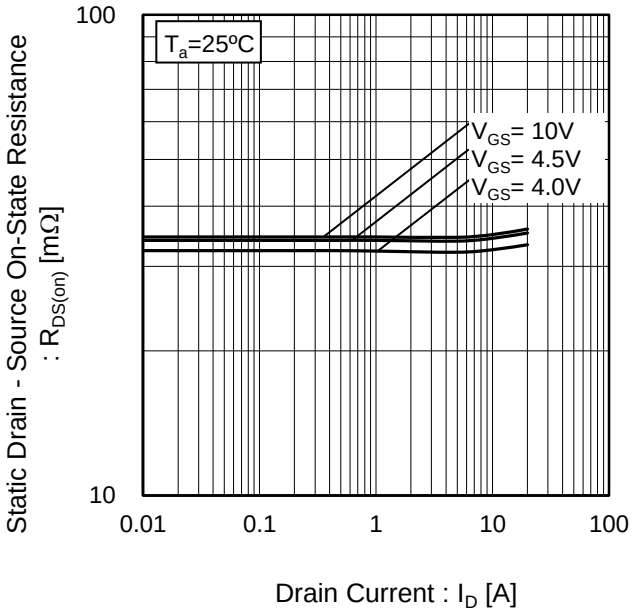
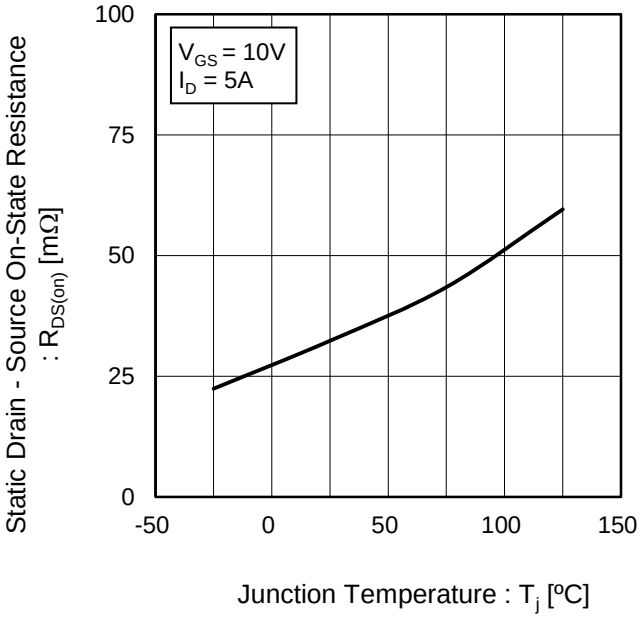


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



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●Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

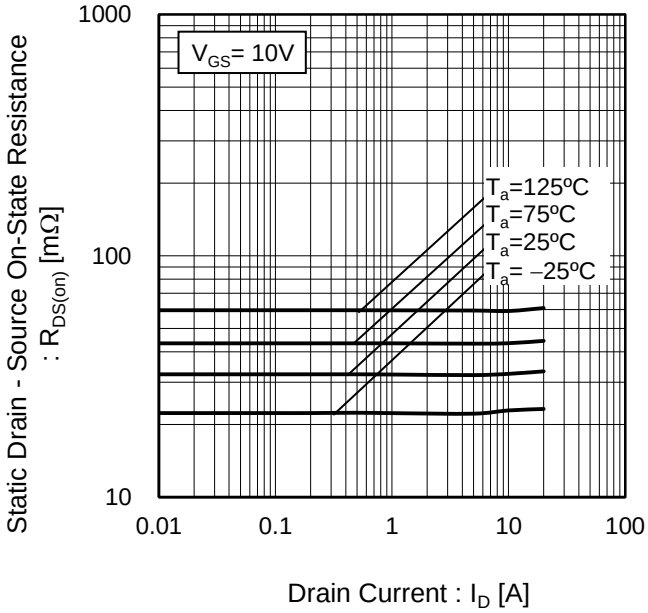


Fig.16 Static Drain-Source On-State Resistance vs. Drain Current(III)

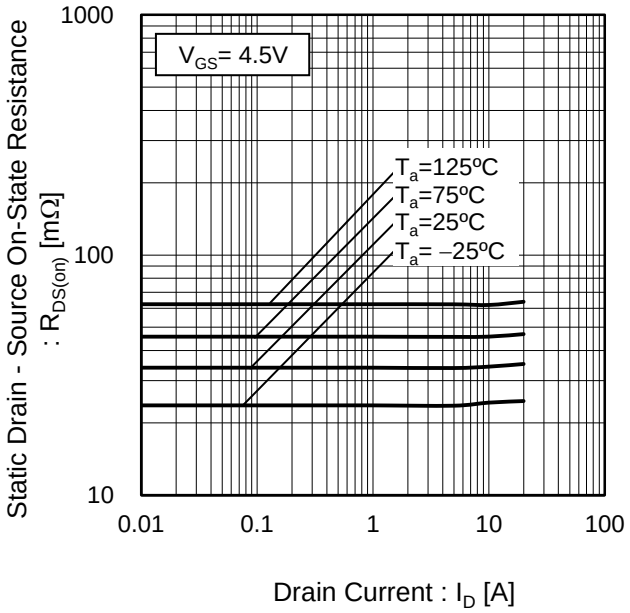


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

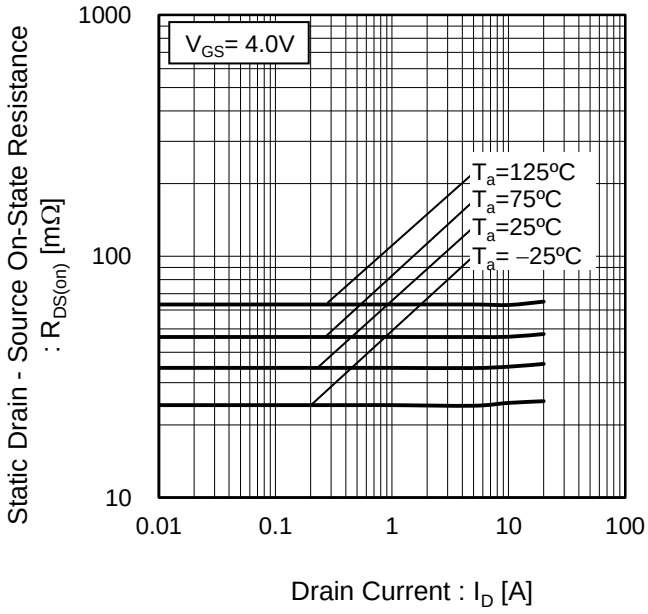
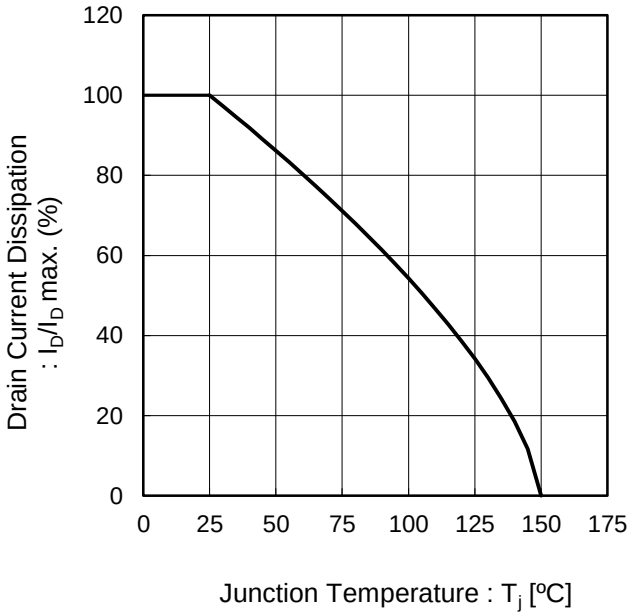


Fig.18 Drain Current Derating Curve



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●Electrical characteristic curves

Fig.19 Typical Capacitance vs. Drain - Source Voltage

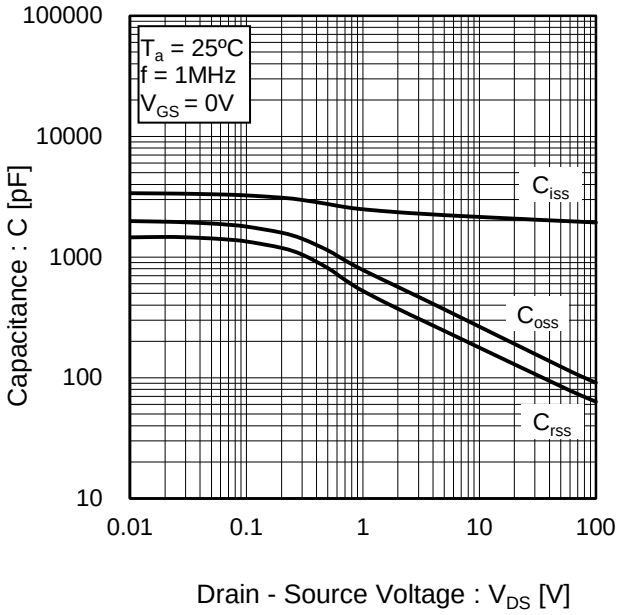


Fig.20 Switching Characteristics

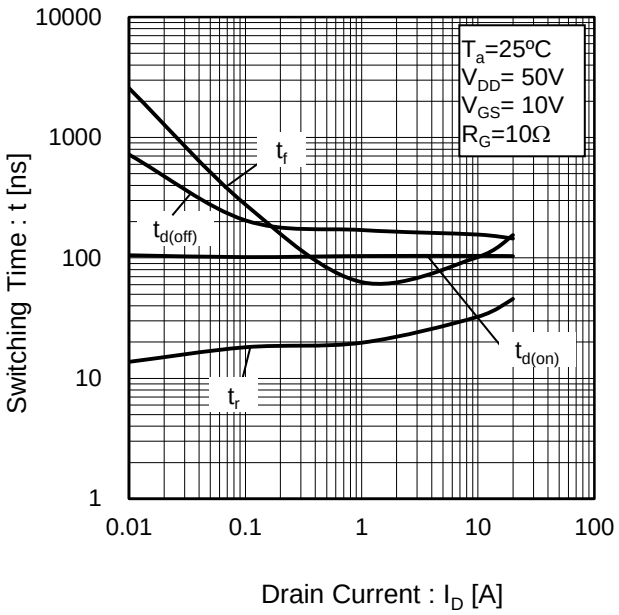


Fig.21 Dynamic Input Characteristics

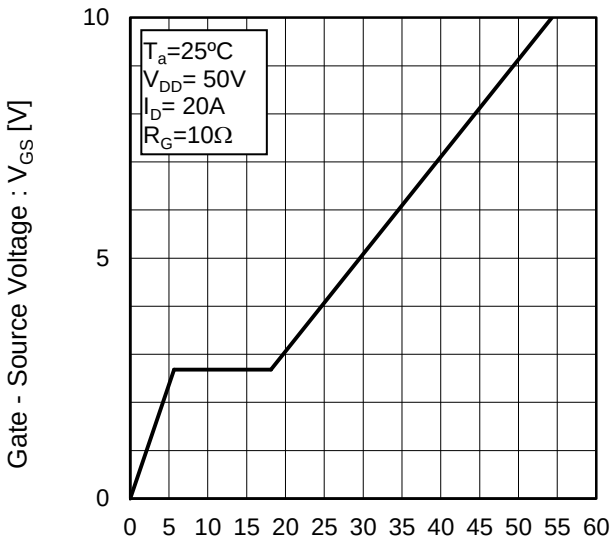
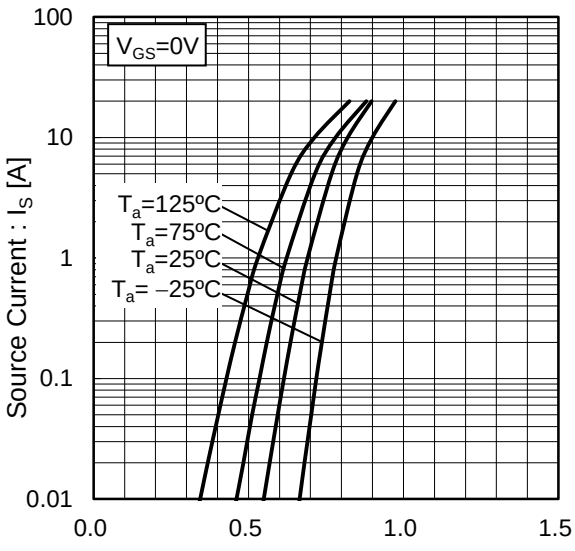


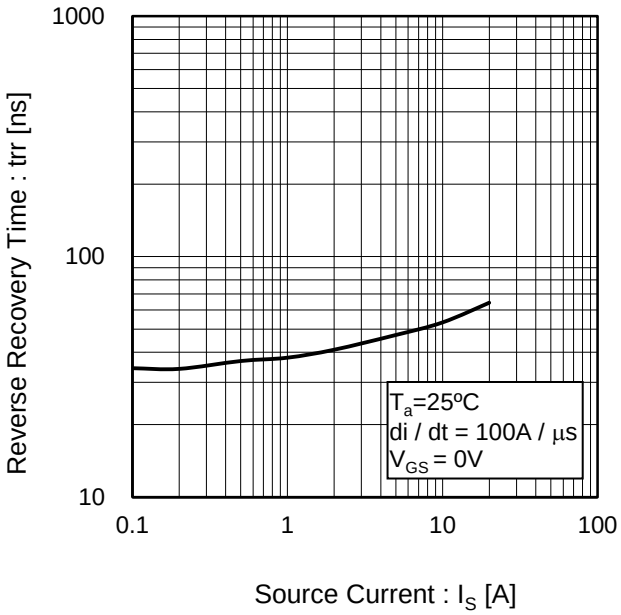
Fig.22 Source Current vs. Source - Drain Voltage



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●Electrical characteristic curves

Fig23 Reverse Recovery Time vs.Source Current



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●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

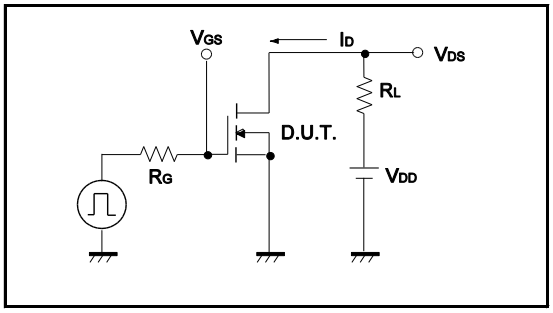


Fig.1-2 Switching Waveforms

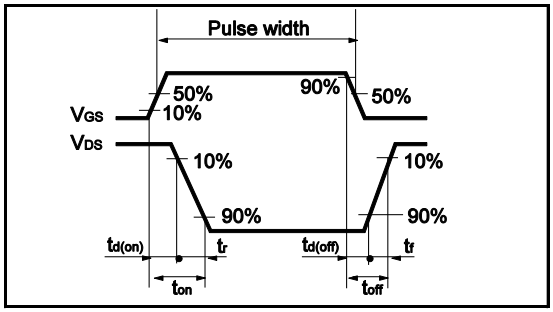


Fig.2-1 Gate Charge Measurement Circuit

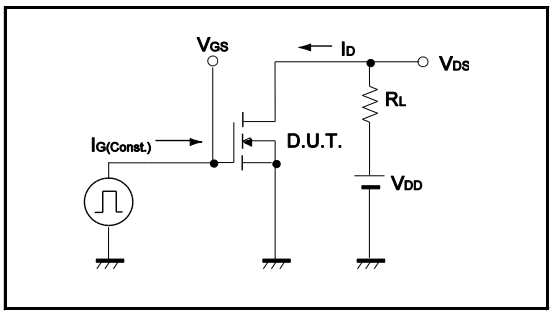


Fig.2-2 Gate Charge Waveform

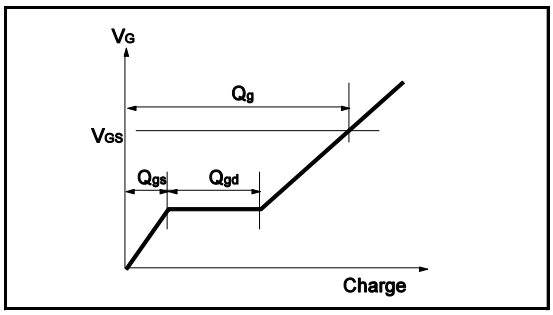


Fig.3-1 Avalanche Measurement Circuit

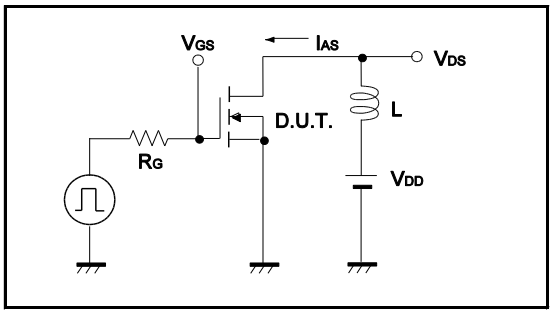
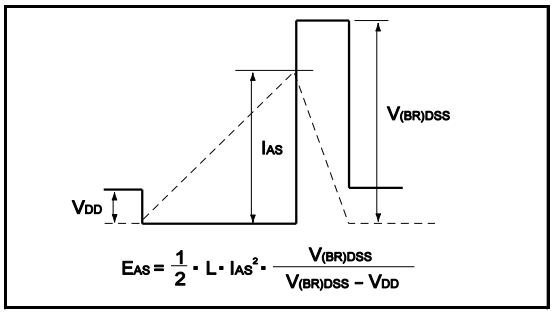


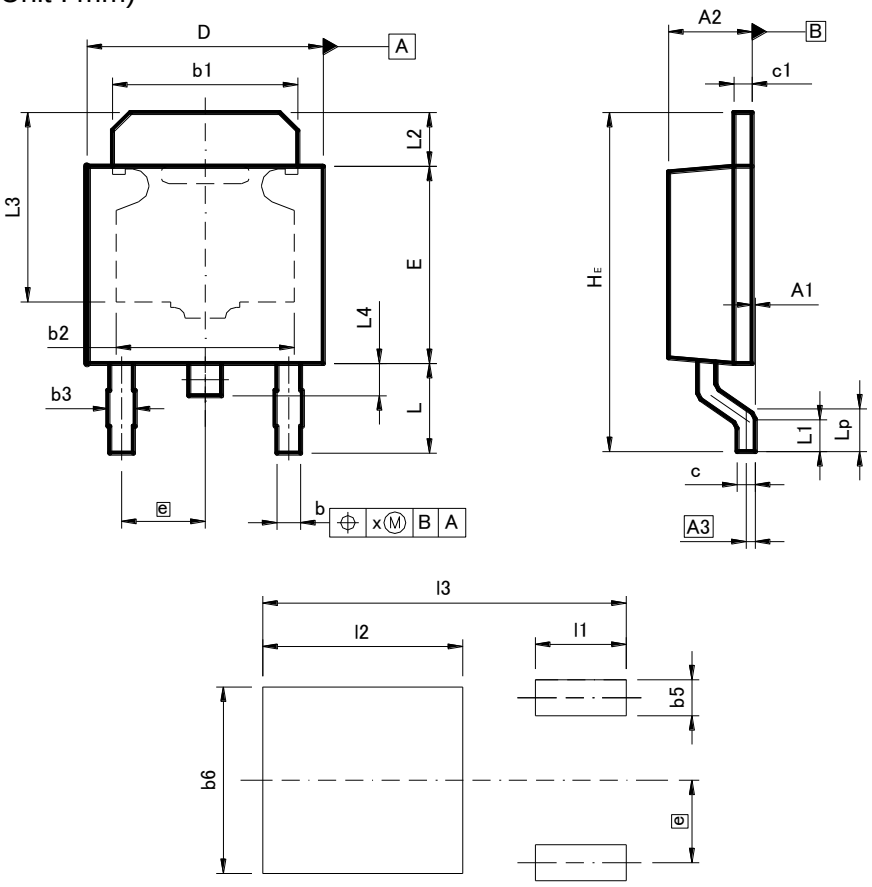
Fig.3-2 Avalanche Waveform



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●**Dimensions** (Unit : mm)

CPT3



DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A1	0.00	0.15	0	0.006
A2	2.20	2.50	0.087	0.098
A3	0.25		0.01	
b	0.55	0.75	0.022	0.03
b1	5.00	5.30	0.197	0.209
b2	5.00		0.20	
b3	0.75		0.03	
c	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
e	2.30		0.09	
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.11
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.035	
Lp	1.00	1.60	0.039	0.063
x	−	0.25	−	0.01

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	−	1.00	−	0.04
b6	−	5.20	−	0.205
l1	−	2.50	−	0.098
l2	−	5.50	−	0.217
l3	−	10.00	−	0.394

Dimension in mm/inches

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